Complementary General Purpose Transistor

The MBT3946DW1T1G device is a spin-off of our popular SOT-23/SOT-323 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-363-6 surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

Features

- h_{FE}, 100-300
- Low $V_{CE(sat)}$, $\leq 0.4 \text{ V}$
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Table 1. MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage (NPN) (PNP)	V _{CEO}	40 -40	Vdc
Collector - Base Voltage (NPN) (PNP)	V _{CBO}	60 -40	Vdc
Emitter - Base Voltage (NPN) (PNP)	V _{EBO}	6.0 -5.0	Vdc
Collector Current – Continuous (NPN) (PNP)	I _C	200 -200	mAdc
Electrostatic Discharge	ESD	HBM Class 2 MM Class B	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 2. THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Package Dissipation (Note 1) T _A = 25°C	P _D	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

^{1.} Device mounted on FR4 glass epoxy printed circuit board using the minimum recommended footprint.

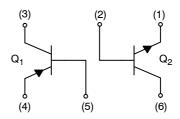


ON Semiconductor®

http://onsemi.com



SOT-363/SC-88 CASE 419B STYLE 1



MBT3946DW1T1**Q1 PNP
Q2 NPN

MARKING DIAGRAM



46 = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MBT3946DW1T1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMBT3946DW1T1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
MBT3946DW1T2G	SC-88 (Pb-Free)	3,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

${\tt MBT3946DW1T1G,\,SMBT3946DW1T1G}$

Table 3. ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS	1		•		
Collector – Emitter Breakdown Voltage (Note 2) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$ $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	(NPN) (PNP)	V _{(BR)CEO}	40 -40	- -	Vdc
Collector – Base Breakdown Voltage ($I_C = 10 \mu Adc, I_E = 0$) ($I_C = -10 \mu Adc, I_E = 0$)	(NPN) (PNP)	V _{(BR)CBO}	60 -40	- -	Vdc
Emitter – Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$) ($I_E = -10 \mu Adc, I_C = 0$)	(NPN) (PNP)	V _{(BR)EBO}	6.0 –5.0	- -	Vdc
Base Cutoff Current $(V_{CE} = 30 \text{ Vdc}, V_{EB} = 3.0 \text{ Vdc})$ $(V_{CE} = -30 \text{ Vdc}, V_{EB} = -3.0 \text{ Vdc})$	(NPN) (PNP)	I _{BL}		50 –50	nAdc
Collector Cutoff Current ($V_{CE} = 30 \text{ Vdc}$, $V_{EB} = 3.0 \text{ Vdc}$) ($V_{CE} = -30 \text{ Vdc}$, $V_{EB} = -3.0 \text{ Vdc}$)	(NPN) (PNP)	I _{CEX}	- -	50 –50	nAdc
ON CHARACTERISTICS (Note 2)	-		•	•	•
DC Current Gain $ \begin{array}{l} (I_C=0.1 \text{ mAdc, } V_{CE}=1.0 \text{ Vdc)} \\ (I_C=1.0 \text{ mAdc, } V_{CE}=1.0 \text{ Vdc)} \\ (I_C=10 \text{ mAdc, } V_{CE}=1.0 \text{ Vdc)} \\ (I_C=50 \text{ mAdc, } V_{CE}=1.0 \text{ Vdc)} \\ (I_C=100 \text{ mAdc, } V_{CE}=1.0 \text{ Vdc)} \\ \end{array} $	(NPN)	h _{FE}	40 70 100 60 30	- 300 - -	-
$ \begin{array}{l} (I_{C} = -0.1 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc)} \\ (I_{C} = -1.0 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc)} \\ (I_{C} = -10 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc)} \\ (I_{C} = -50 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc)} \\ (I_{C} = -100 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc)} \\ \end{array} $	(PNP)		60 80 100 60 30	- 300 - -	
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$)	(NPN)	V _{CE(sat)}	-	0.2 0.3	Vdc
$(I_C = -10 \text{ mAdc}, I_B = -1.0 \text{ mAdc})$ $(I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$	(PNP)		- -	-0.25 -0.4	
Base – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$)	(NPN)	V _{BE(sat)}	0.65 -	0.85 0.95	Vdc
$(I_C = -10 \text{ mAdc}, I_B = -1.0 \text{ mAdc})$ $(I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$	(PNP)		-0.65 -	-0.85 -0.95	
SMALL-SIGNAL CHARACTERISTICS	-		•	•	•
Current – Gain – Bandwidth Product ($I_C = 10$ mAdc, $V_{CE} = 20$ Vdc, $f = 100$ MHz) ($I_C = -10$ mAdc, $V_{CE} = -20$ Vdc, $f = 100$ MHz)	(NPN) (PNP)	f _T	300 250	- -	MHz
Output Capacitance $(V_{CB}=5.0~Vdc,~I_E=0,~f=1.0~MHz)$ $(V_{CB}=-5.0~Vdc,~I_E=0,~f=1.0~MHz)$	(NPN) (PNP)	$C_{ m obo}$	- -	4.0 4.5	pF
Input Capacitance $(V_{EB} = 0.5 \text{ Vdc}, I_{C} = 0, f = 1.0 \text{ MHz})$ $(V_{EB} = -0.5 \text{ Vdc}, I_{C} = 0, f = 1.0 \text{ MHz})$	(NPN) (PNP)	C _{ibo}	- -	8.0 10.0	pF
Input Impedance (V_{CE} = 10 Vdc, I_{C} = 1.0 mAdc, f = 1.0 kHz) (V_{CE} = -10 Vdc, I_{C} = -1.0 mAdc, f = 1.0 kHz)	(NPN) (PNP)	h _{ie}	1.0 2.0	10 12	kΩ
Voltage Feedback Ratio $(V_{CE} = 10 \text{ Vdc}, I_{C} = 1.0 \text{ mAdc}, f = 1.0 \text{ kHz})$ $(V_{CE} = -10 \text{ Vdc}, I_{C} = -1.0 \text{ mAdc}, f = 1.0 \text{ kHz})$	(NPN) (PNP)	h _{re}	0.5 0.1	8.0 10	X 10 ⁻⁴
Small – Signal Current Gain (V_{CE} = 10 Vdc, I_{C} = 1.0 mAdc, f = 1.0 kHz) (V_{CE} = -10 Vdc, I_{C} = -1.0 mAdc, f = 1.0 kHz)	(NPN) (PNP)	h _{fe}	100 100	400 400	-

Table 4. ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (continued)

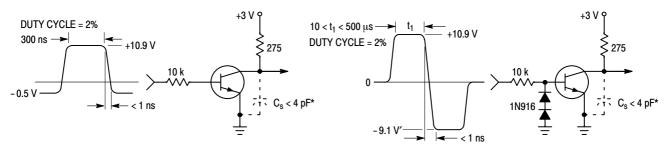
Characteristic		Symbol	Min	Max	Unit
Output Admittance (V _{CE} = 10 Vdc, I _C = 1.0 mAdc, f = 1.0 kHz)	(NPN)	h _{oe}	1.0	40	μmhos
$(V_{CE} = -10 \text{ Vdc}, I_{C} = -1.0 \text{ mAdc}, f = 1.0 \text{ kHz})$	(PNP)		3.0	60	
Noise Figure		NF			dB
$(V_{CE} = 5.0 \text{ Vdc}, I_C = 100 \mu\text{Adc}, R_S = 1.0 \text{ k}\Omega, f = 1.0 \text{ kHz})$ $(V_{CE} = -5.0 \text{ Vdc}, I_C = -100 \mu\text{Adc}, R_S = 1.0 \text{ k}\Omega, f = 1.0 \text{ kHz})$	(NPN) (PNP)		-	5.0 4.0	

SWITCHING CHARACTERISTICS

Delay Time	$(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc})$ $(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc})$	(NPN) (PNP)	t _d	- -	35 35	20
Rise Time	$(I_C = 10 \text{ mAdc}, I_{B1} = 1.0 \text{ mAdc})$ $(I_C = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$	(NPN) (PNP)	t _r	- -	35 35	ns
Storage Time	$(V_{CC} = 3.0 \text{ Vdc}, I_{C} = 10 \text{ mAdc})$ $(V_{CC} = -3.0 \text{ Vdc}, I_{C} = -10 \text{ mAdc})$	(NPN) (PNP)	t _s	-	200 225	20
Fall Time	$(I_{B1} = I_{B2} = 1.0 \text{ mAdc})$ $(I_{B1} = I_{B2} = -1.0 \text{ mAdc})$	(NPN) (PNP)	t _f	- -	50 75	ns

^{2.} Pulse Test: Pulse Width \leq 300 μ s; Duty Cycle \leq 2.0%.

(NPN)



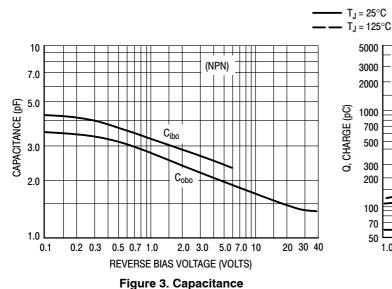
^{*} Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time **Equivalent Test Circuit**

Figure 2. Storage and Fall Time **Equivalent Test Circuit**

TYPICAL TRANSIENT CHARACTERISTICS

- T_{.1} = 25°C



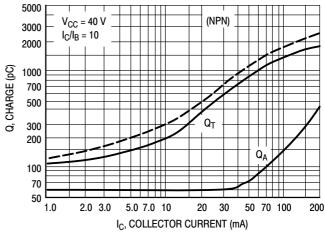


Figure 4. Charge Data

(NPN)

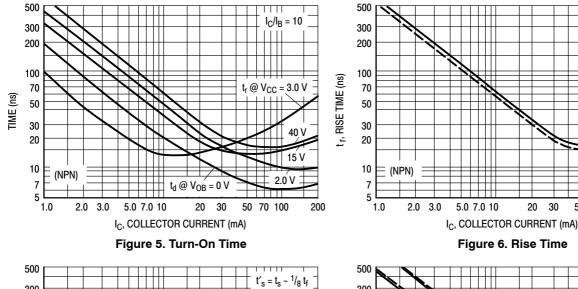


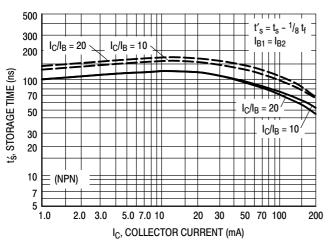
Figure 6. Rise Time

 $V_{CC} = 40 \text{ V}$

 $I_C/I_B = 10$

50 70 100

200



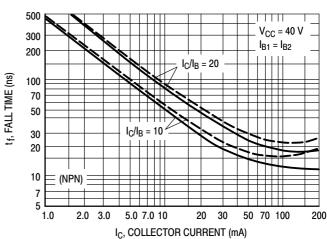


Figure 7. Storage Time

Figure 8. Fall Time

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS **NOISE FIGURE VARIATIONS**

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$

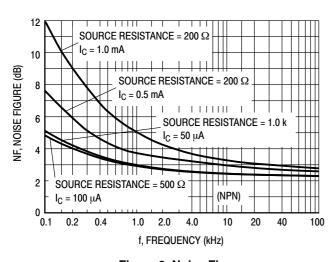


Figure 9. Noise Figure

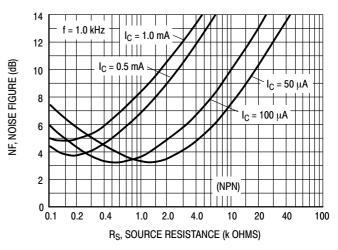
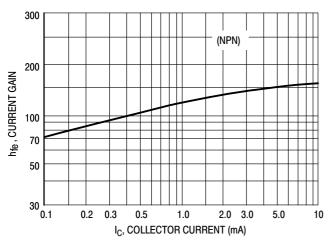


Figure 10. Noise Figure

(NPN) h PARAMETERS

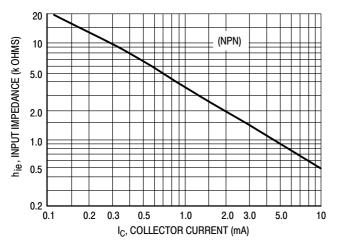
 $(V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$



100 h_{0e}, OUTPUT ADMITTANCE (μmhos) (NPN) 50 20 10 5 2 0.1 0.2 0.5 2.0 3.0 5.0 10 1.0 IC, COLLECTOR CURRENT (mA)

Figure 11. Current Gain

Figure 12. Output Admittance



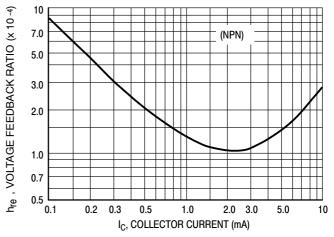


Figure 13. Input Impedance

Figure 14. Voltage Feedback Ratio

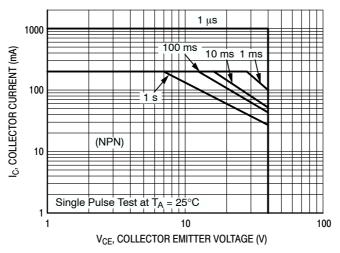


Figure 15. Safe Operating Area

(NPN) TYPICAL STATIC CHARACTERISTICS

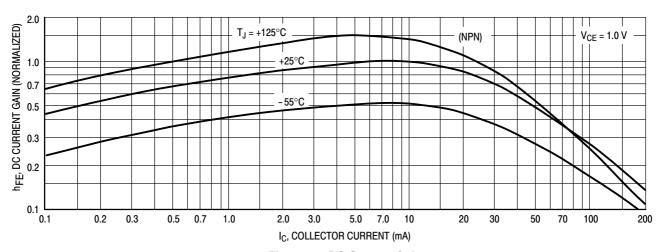


Figure 16. DC Current Gain

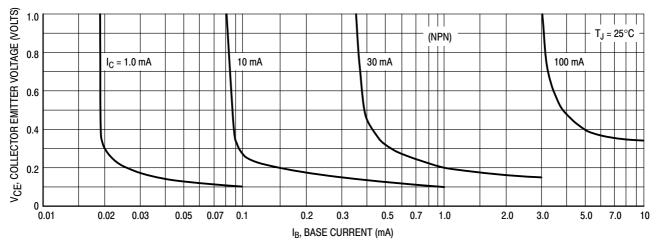


Figure 17. Collector Saturation Region

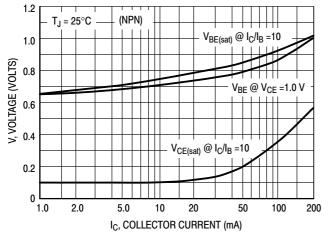


Figure 18. "ON" Voltages

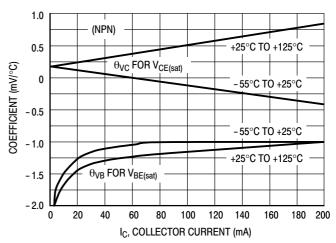
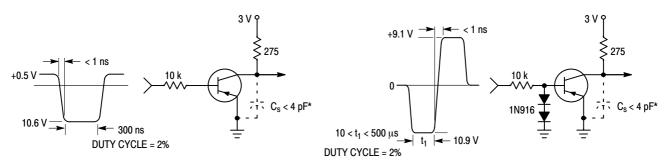


Figure 19. Temperature Coefficients

(PNP)



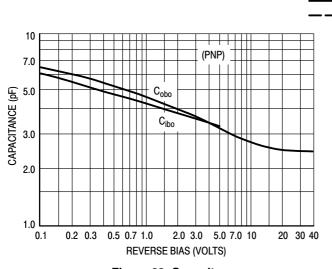
* Total shunt capacitance of test jig and connectors

Figure 20. Delay and Rise Time Equivalent Test Circuit

Figure 21. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS

T_J = 25°C
 T_J = 125°C





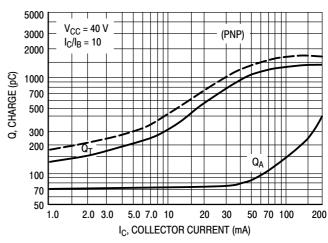


Figure 23. Charge Data

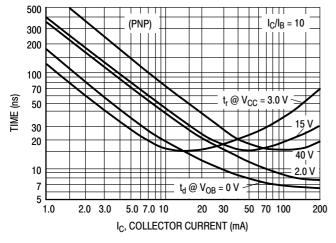


Figure 24. Turn-On Time

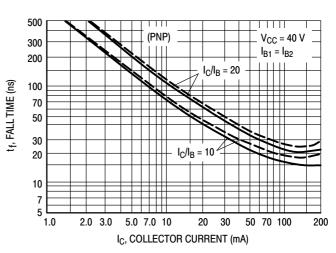
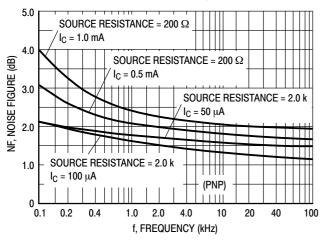


Figure 25. Fall Time

(PNP)

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



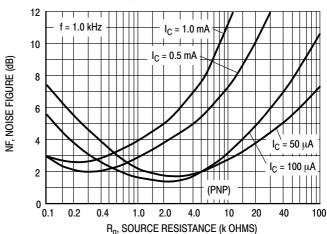
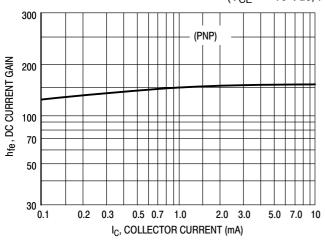


Figure 26.

Figure 27.

h PARAMETERS

 $(V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$



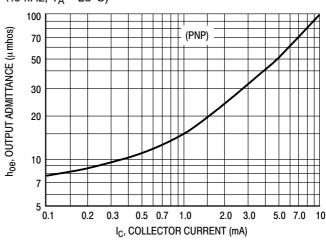


Figure 28. Current Gain

20 (PNP) h ie, INPUT IMPEDANCE (k OHMS) 10 7.0 5.0 3.0 2.0 1.0 0.7 0.5 0.3 0.1 0.2 0.3 0.5 0.7 1.0 2.0 3.0 5.0 7.0 10 IC, COLLECTOR CURRENT (mA)

Figure 29. Output Admittance

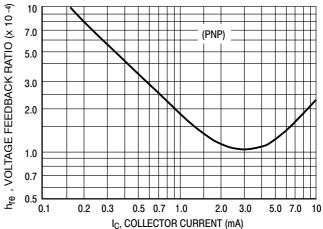


Figure 30. Input Impedance

Figure 31. Voltage Feedback Ratio

(PNP)

TYPICAL STATIC CHARACTERISTICS

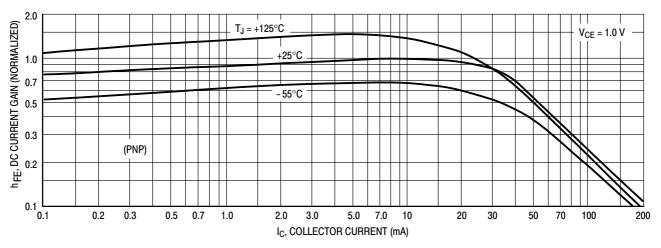


Figure 32. DC Current Gain

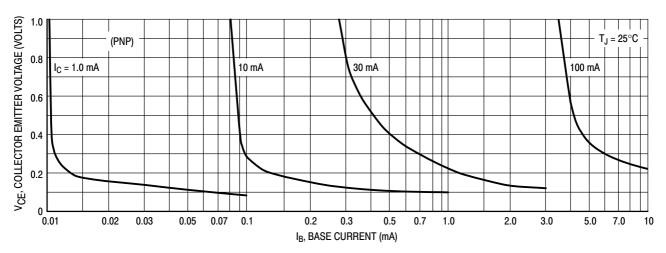


Figure 33. Collector Saturation Region

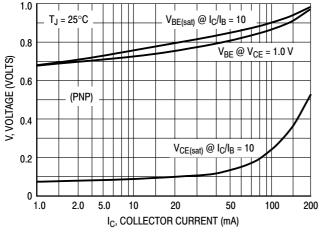


Figure 34. "ON" Voltages

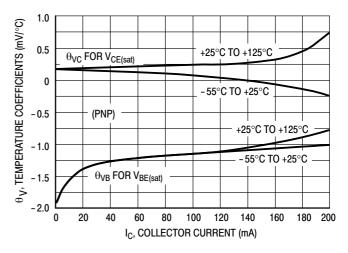


Figure 35. Temperature Coefficients

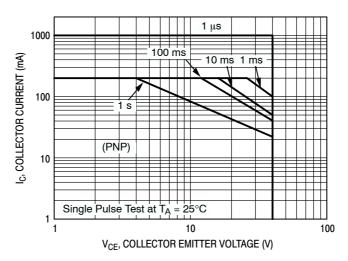
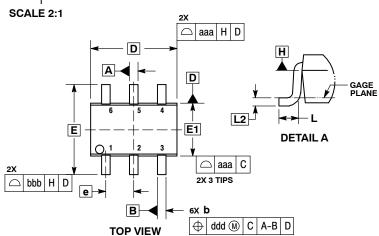
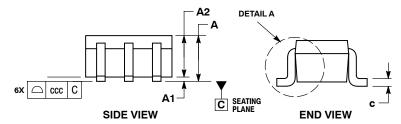


Figure 36. Safe Operating Area

SC-88/SC70-6/SOT-363 CASE 419B-02 **ISSUE Y**

DATE 11 DEC 2012





GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

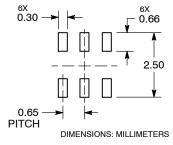
= Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

- *Date Code orientation and/or position may vary depending upon manufacturing location.
- *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42985B	Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SC-88/SC70-6/SOT-363		PAGE 1 OF 2	

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- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H. DATUMS A AND B ARE DETERMINED AT DATUM H. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.

- DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION 6 AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MILLIMETERS INCHES			3		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α		-	1.10			0.043
A1	0.00	-	0.10	0.000		0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65 BSC			0	.026 BS	С
L	0.26	0.36	0.46	0.010	0.014	0.018
L2		0.15 BSC 0.006 BSC			SC	
aaa		0.15			0.006	
bbb	0.30				0.012	
ccc		0.10			0.004	
ddd		0.10			0.004	

SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

DATE 11 DEC 2012

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13: PIN 1. ANODE 2. N/C 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 14: PIN 1. VREF 2. GND 3. GND 4. IOUT 5. VEN 6. VCC	STYLE 15: PIN 1. ANODE 1 2. ANODE 2 3. ANODE 3 4. CATHODE 3 5. CATHODE 2 6. CATHODE 1	STYLE 16: PIN 1. BASE 1 2. EMITTER 2 3. COLLECTOR 2 4. BASE 2 5. EMITTER 1 6. COLLECTOR 1	STYLE 17: PIN 1. BASE 1 2. EMITTER 1 3. COLLECTOR 2 4. BASE 2 5. EMITTER 2 6. COLLECTOR 1	STYLE 18: PIN 1. VIN1 2. VCC 3. VOUT2 4. VIN2 5. GND 6. VOUT1
STYLE 19: PIN 1. I OUT 2. GND 3. GND 4. V CC 5. V EN 6. V REF	STYLE 20: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR	STYLE 21: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. N/C 6. CATHODE 1	STYLE 22: PIN 1. D1 (i) 2. GND 3. D2 (i) 4. D2 (c) 5. VBUS 6. D1 (c)	STYLE 23: PIN 1. Vn 2. CH1 3. Vp 4. N/C 5. CH2 6. N/C	STYLE 24: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE
STYLE 25: PIN 1. BASE 1 2. CATHODE 3. COLLECTOR 2 4. BASE 2 5. EMITTER 6. COLLECTOR 1	STYLE 26: PIN 1. SOURCE 1 2. GATE 1 3. DRAIN 2 4. SOURCE 2 5. GATE 2 6. DRAIN 1	STYLE 27: PIN 1. BASE 2 2. BASE 1 3. COLLECTOR 1 4. EMITTER 1 5. EMITTER 2 6. COLLECTOR 2	STYLE 28: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6. DRAIN	STYLE 29: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE/ANODE 6. CATHODE	STYLE 30: PIN 1. SOURCE 1 2. DRAIN 2 3. DRAIN 2 4. SOURCE 2 5. GATE 1 6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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